ΡΛΝ	ĴΪΤ
	SEMI CONDUCTOR

Unit : inch(mm)

0.024(0.60)

2

PJE8405 30V P-Channel Enhancement Mode MOSFET – ESD Protected SOT-523 Voltage -30 V Current -0.5A 0.013(0.33) 0.009(0.23) Features 0.044(1.10) 0.035(0.90) 0.067(1.70) 0.059(1.50) RDS(ON), VGS@-4.5V, ID@-0.5A<390mΩ 0.052(1.30) RDS(ON), VGS@-2.5V, ID@-0.3A<560mΩ 0.067(1.70) RDS(ON), VGS@-1.8V, ID@-0.1A<990mΩ .007(0.17) . 0.059(1.50) Advanced Trench Process Technology Specially Designed for Switch Load, PWM Application, etc. ESD Protected 2KV HBM • Lead free in compliance with EU RoHS 2011/65/EU directive. Green molding compound as per IEC61249 Std. 0.012(0.30) (Halogen Free) D **Mechanical Data** 3 • Case: SOT-523 Package Terminals: Solderable per MIL-STD-750, Method 2026 • Approx. Weight: 0.00007 ounces, 0.002 grams Marking: E05 1

Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	-30	V
Gate-Source Voltage		V _{GS}	<u>+</u> 8	V
Continuous Drain Current		I _D	-0.5	А
Pulsed Drain Current		I _{DM}	-2.0	А
Power Dissipation	T _a =25°C	P _D	300	mW
	Derate above 25°C		2.4	mW/°C
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C
Typical Thermal resistance - Junction to Ambient (Note 3)		R _{eJA}	417	°C/W
		007		0/00



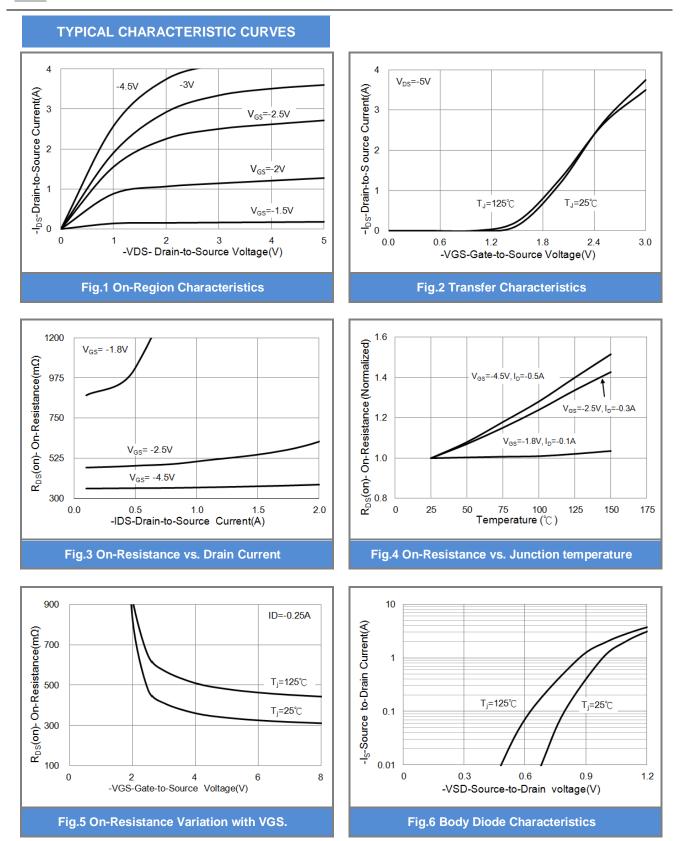
Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static			•			
Drain-Source Breakdown Voltage	BV_{DSS}	V _{GS} =0V, I _D =-250uA	-30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250$ uA	-0.5	-0.98	-1.3	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-4.5V, I _D =-0.5A	-	318	390	mΩ
		V _{GS} =-2.5V, I _D =-0.3A	-	427	560	
		V _{GS} =-1.8V, I _D =-0.1A	-	853	990	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V	-	-0.01	-1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 8V, V _{DS} =0V	-	<u>+</u> 3.2	<u>+</u> 10	uA
Dynamic						
Total Gate Charge	Q_{g}	V _{DS} =-15V, I _D =-0.5A, V _{GS} =-4.5V ^(Note 1,2)	-	1.6	-	nC
Gate-Source Charge	Q_gs		-	0.5	-	
Gate-Drain Charge	Q_gd		-	0.3	-	
Input Capacitance	Ciss	V _{DS} =-15V, V _{GS} =0V, f=1.0MHZ	-	137	-	pF
Output Capacitance	Coss		-	23	-	
Reverse Transfer Capacitance	Crss	I=I.UIVIHZ	-	10	-	
Switching						
Turn-On Delay Time	td _(on)		-	11	-	ns
Turn-On Rise Time	tr	V_{DD} =-15V, I _D =-0.5A, V_{GS} =-4.5V, R_{G} =6 Ω ^(Note 1.2)	-	52	-	
Turn-Off Delay Time	td _(off)		-	65	-	
Turn-Off Fall Time	tf	R _G =0Ω	-	46	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	I _S		-	-	-0.4	A
Diode Forward Current						
Diode Forward Voltage	V_{SD}	I _S =-1.0A, V _{GS} =0V	-	-0.93	-1.2	V

NOTES :

- 1. Pulse width<u><</u>300us, Duty cycle<u><</u>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R_{®JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





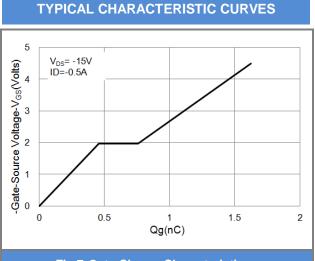


Fig.7 Gate-Charge Characteristics

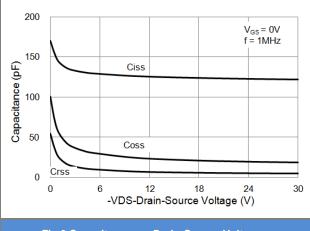
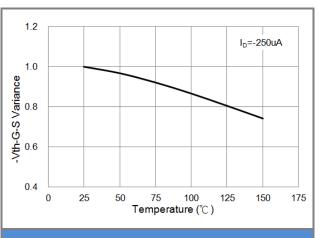


Fig.9 Capacitance vs. Drain-Source Voltage





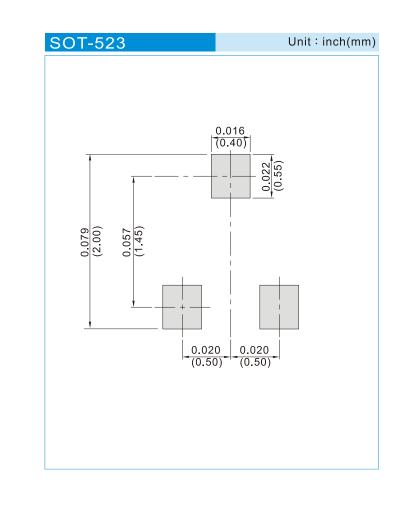




PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJE8405_R1_00001	SOT-523	4K pcs / 7" reel	E05	Halogen free

MOUNTING PAD LAYOUT







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